## **Electronic Supplementary Information**

# Plasmon-enhanced dye-sensitized solar cells using SiO<sub>2</sub> spheres deco rated with tightly assembled silver nanoparticles

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#### 1. Materials

Tetraethylorthosilicate (TEOS), 3-mercaptopropyl trimethoxysilane (MPTS), ethylene glycol (E G), poly(vinyl pyrrolidone) (PVP, MW ~40,000), silver nitrate (AgNO<sub>3</sub>, 99.99+%), octylamine ( OA), and all components of electrolyte were purchased from Sigma-Aldrich and used without fur ther purification. Ammonium hydroxide (NH<sub>4</sub>OH, 27%) and ethanol (98%) were purchased from Daejung Chemical. N719 (cis-diisothiocyanato-bis(2,2'-bipyridyl-4,4'-dicarboxylato) ruthenium( II) bis(tetrabutylammonium)) dye was purchased from Solaronix.

#### 2. Preparation of SiO<sub>2</sub> spheres decorated with tightly assembled silver nanoparticles

Tetraethylorthosilicate (TEOS, 1.6 mL) was dissolved in 40 mL of absolute ethanol, followed b y addition of a 3 mL portion of aqueous ammonium hydroxide (27%). The resulting mixture was vigorously stirred using magnetic bar for 20 h at 25 °C. The resulting silica spheres were centrifu

ged and then washed with ethanol five times to remove the excess reagents. These silica spheres were then functionalized with thiol group. Silica spheres (150 mg) were dispersed in 3 mL ethan ol containing 150 µL of MPTS and 30 µL of aqueous ammonium hydroxide (27 %). The mixture was stirred for 12 h at 25 °C. The resulting MPTS-treated silica spheres were centrifuged and wa shed with ethanol several times. In order to fabricate SiO<sub>2</sub> spheres decorated with tightly assemble ed silver nanoparticles (SiO<sub>2</sub>-t-Ag), 25 mg portion of MPTS-treated silica spheres was thoroughl y dispersed in 100 mL of AgNO<sub>3</sub> solution (3.5 mM in ethylene glycol). An 82.7 µL of octylamin e (5 mM) was then rapidly added into the MPTS-treated silica spheres dispersion. The resulting mixture was stirred for 1 h at 25 °C. Afterwards, SiO<sub>2</sub> spheres decorated with tightly assembled s ilver nanoparticles were centrifuged and washed with ethanol five times for purification. In case of SiO<sub>2</sub> spheres decorated with sparsely assembled silver nanoparticles (SiO<sub>2</sub>-s-Ag), 50 mg of M PTS-treated silica spheres was used in the same reaction condition except amount of SiO<sub>2</sub> sphere.

For silica coating to SiO<sub>2</sub> spheres decorated with tightly assembled silver nanoparticles, a 1 mL portion of MPTS solution (2 mM in ethanol) was added into 1 mg of silver nanoparticles-decorat ed silica spheres. The resulting dispersion was shaken for 1 h at 25 °C. The silver nanoparticles-d ecorated silica spheres were transferred to 50 mL of 2-propanol with 1 mg of PVP (MW ~40,000). A 2 ml of ammonium hydroxide was added to the reaction mixture under vigorous stirring, foll owed by the addition of 250  $\mu$ L of TEOS solution (TEOS/2-propanol, 0.8 v/v %) in two separate portions with a time interval of 30 min. After adding the TEOS, the mixture was allowed to react for 12 h. Finally, the resulting silica coated SiO<sub>2</sub> spheres decorated with tightly assembled silver nanoparticles (SiO<sub>2</sub>-t-Ag@SiO<sub>2</sub>) were centrifuged and washed with ethanol five times.

#### 3. Preparation of the photoanodes

F-doped SnO<sub>2</sub> (FTO) glass plates (8 Ω/cm<sup>2</sup>, Pilkington TEC glass<sup>TM</sup>) were cleaned in detergent s

olution using an ultrasonic bath for 20 min and washed with tap water and ethanol. The plates we re immersed in 40 mM TiCl<sub>4</sub> aqueous solution at 70 °C for 30 min and rinsed with DI water and ethanol. The photoanode pastes incorporating SiO<sub>2</sub>-t-Ag@SiO<sub>2</sub> or SiO<sub>2</sub> were prepared by simple mixing. The SiO<sub>2</sub>-t-Ag@SiO<sub>2</sub> or SiO<sub>2</sub> in ethanol solutions (SiO<sub>2</sub> to TiO<sub>2</sub> ratio = 1, 3 wt%) were mixed with commercial TiO<sub>2</sub> pastes (Dyesol, DSL 18NR-T), and they were stirred for 2 h and di spersed by ultrasonicator. Then ethanol was removed by rotary evaporator. The photoanode films were prepared by Doctor blade printing on TiCl<sub>4</sub>-treated FTO plates, and annealed at 500 °C for 15 min. The thickness and the active area of photoanode films were controlled to 6 µm and 0.202 5 cm<sup>2</sup>.

#### 4. Assembly of dye-sensitized solar cells

Cathodes were prepared by thermal deposition. A drop of 10 mM H<sub>2</sub>PtCl<sub>6</sub> in 2-propanol was spr ead on FTO glass plate by spin coating followed by heating to 400 °C for 15 min. The prepared p hotoanode was assembled with Pt counter electrode (with drilled hole) into sandwich-type cell us ing thermal adhesive film (Surlyn: 30  $\mu$ m, Dupont). The electrolyte solution was prepared by mix ing 0.60 M 1-butyl-3-methylimidazolium iodide, 0.03 M I<sub>2</sub>, 0.10 M guanidinium thiocyanate and 4-*tert*-butylpyridine in a mixture of acetonitrile and valeronitrile (v/v, 85:15). Before the measure ment of photovoltaic performance, a mask of 0.16 cm<sup>2</sup> was attached on the outside of FTO glass having the photoanode.

#### 5. Instruments

UV-Vis absorption spectra of the particles in solutions were collected by a UV-Visible spectro

meter (Mecasys Co. Ltd., Optizen 2120 UV). UV-vis absorption and reflectance spectra of the ph otoanodes were collected by UV-vis spectrometer (Jasco, V-670) with integrated sphere. A TE M images were obtained using EF-TEM (Carl Zeiss, LIBRA 120). The photovoltaic performance was measured using a 500 W xenon lamp (XIL model 05A50KS source measure units and an A M 1.5 filter) at a power of 100 mW/cm<sup>2</sup>. The incident photon-to-current efficiency was measured using solar cell quantum efficiency measurement system (QEX10, PV measurements, Inc.).

6. Individual silver nanoparticles and SiO<sub>2</sub> spheres decorated with sparsely assembled silve r nanoparticles (SiO<sub>2</sub>-s-Ag)



**Fig. S1** TEM image of (a) individual Ag NPs and (b) SiO<sub>2</sub> spheres decorated with sparsely assembled silver nanopar ticles (SiO<sub>2</sub>-s-Ag).



**Fig. S2** UV-vis absorption spectra of SiO<sub>2</sub> spheres decorated with sparsely assembled silver nanoparticles (SiO<sub>2</sub>-s-A g) and SiO<sub>2</sub> spheres decorated with tightly assembled silver nanoparticles (SiO<sub>2</sub>-t-Ag).

#### 7. UV-vis absorption and diffused reflectance spectra of photoanodes before dye-adsorption



**Fig. S3** (a) UV-vis absorption spectra of photoanodes before dye-adsorption (b) UV-vis diffused reflectance spectra of photoanodes before dye-adsorption.

#### 8. Optical and photoelectrochemical properties of 5 wt% SiO<sub>2</sub>-t-Ag@SiO<sub>2</sub> photoanode cell

To obtain an optimized performance, paste containing 5 wt% of SiO<sub>2</sub>-t-Ag@SiO<sub>2</sub> was prepared. The photoanode containing 5 wt% of SiO<sub>2</sub>-t-Ag@SiO<sub>2</sub> shows stronger UV-vis absorption becaus e of higher concentration of SiO<sub>2</sub>-t-Ag@SiO<sub>2</sub>. (Fig. S4(a)) However, It exhibit lower photo-curre nt and power conversion efficiency than 3 wt% cell. (Fig. S4(b,c)) It is mainly due to excessive li ght absorption by SiO<sub>2</sub>-t-Ag@SiO<sub>2</sub>, which isn't delivered to the sensitizer completely.



Fig. S4 (a) UV-vis absorption spectra of photoanodes, (b) J-V curves of DSSCs, (c) IPCE spectra of DSSCs.

#### 9. Discrete Dipole Approximation (DDA) simulations

To further study the origin of the increased short-circuit current, we simulated the electric filed distribution around the light-illuminated  $SiO_2$  sphere decorated with silver nanoparticles by using the DDSCAT 7.1 package [1]. In our simulation, isotropic dipoles are evenly placed in silver nan oparticles at dipole–dipole distances of 2 nm. These silver nanoparticles were 20 nm in diameter, and the distance between each silver nanoparticle is about 2 nm, and silica core was 160 nm in di ameter. From this DDA simulation results, a strong electric field at the surface of silver was obse rved. Also, the enhanced field was confirmed outside of the SiO<sub>2</sub> shell. The enhanced electric field at around silver nanoparticle increases the absorption of N719 dye adsorbed on adjacent TiO<sub>2</sub>.



Fig. S5 (a) Electric field intensity distribution in  $SiO_2$  sphere decorated with silver nanoparticles, (b) showing a clos e up silver nanoparticle surface, (c) Intensity of electric fields with respect to the distance from silver nanoparticle.

10. Photovoltaic characteristics of DSSCs with 12 μm photoanodes (TiO<sub>2</sub> and 3 wt% SiO<sub>2</sub>-t-Ag@SiO<sub>2</sub>)



Fig. S6 J-V curves of DSSCs with 12 µm photoanodes.

Table S1 Photovoltaic parameters of DSSCs with 12 µm photoanodes

Photoanode	$J_{SC}$ (mA/cm <sup>2</sup> )	$V_{OC}\left(\mathbf{V}\right)$	ſſ	η (%)
TiO <sub>2</sub> (12 μm)	14.84	0.703	0.71	7.44
3 wt% SiO <sub>2</sub> -t-Ag@SiO <sub>2</sub> (12 $\mu$ m)	16.18	0.731	0.70	8.31

#### 11. Absorbed photon-to-current conversion efficiency (APCE)

The absorbed photon-to-current conversion efficiency (APCE) was calculated by dividing measured incident photon-to-current conversion efficiency (IPCE) by light harvesting efficiency (LHE =  $1 - 10^{-A}$ , with A being the absorbance of the film). APCE spectra of samples are similar because the plasmonic particle does not affect the quantum yield for the electron injection or efficiency of transporting injected electrons, whereas total amount of absorbed photons is affected. At wavelength above 550 nm, APCE of 3 wt% SiO<sub>2</sub>-t-Ag@SiO<sub>2</sub> is lower than that of TiO<sub>2</sub>, because SiO<sub>2</sub>-t-Ag@SiO<sub>2</sub> absorbs too many photons that do not participate in charge

generation.



Fig. S7 Absorbed photon-to-current conversion efficiency

### References

[1] B. T. Draine, P. J. Flatau, 2010, "User Guide to the Discrete Dipole Approximation Code DD

SCAT 7.1", http:// http://arxiv.org/abs/1002.1505